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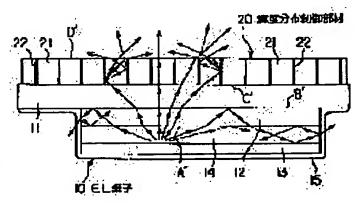
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(54) SURFACE LIGHT EMITTING BODY AND LIQIUD CRYSTAL DISPLAY DEVICE USING IT (57) Abstract:

PROBLEM TO BE SOLVED: To improve luminescence distribution of emission light by increasing luminescence of light to be emitted in a predetermined direction as a surface light emitting body employing an EL element and widening an emission angle range in which the emission light of sufficient luminescence can be obtained. SOLUTION: An emission face of an EL element 10 is provided with a luminescence distribution control member 20 consisting of a plurality of transparent parts 21 arrayed along a plane direction and a scattering reflection membrane 22 sandwiched between these transparent parts 21, the light incident toward a diagonal direction, of the light emitting the EL element and incident to the transparent parts 21 of the luminescence distribution control member 20 is advanced straight and emitted, and the light emitted toward the diagonal direction is scattered by the scattering reflection membrane 22 and is emitted.



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CLAIMS

[Claim(s)]

[Claim 1] The field emitter characterized by preparing luminance distribution control-section material with the property which the light which the light which carried out incidence toward the predetermined direction among the incident light from the rear face which counters the outgoing radiation side went straight on, carried out [light] outgoing radiation to the front face, and carried out incidence toward other directions is scattered on the outgoing radiation side of an electroluminescent element, and carries out outgoing radiation to said front face.

[Claim 2] Said luminance distribution control-section material is a field emitter according to claim 1 characterized by being on the field where it consists of scatter reflection film inserted between the side faces of two or more area pellucida located in a line along the direction of a field, and these area pellucida, and said scatter reflection film met in said predetermined direction.

[Claim 3] The rear face of said luminance distribution control-section material is a field emitter according to claim 2 characterized by having stuck to the outgoing radiation side of said electroluminescent element.

[Claim 4] The refractive index of the area pellucida of said luminance distribution

control-section material is a field emitter according to claim 3 characterized by being almost the same as the refractive index by the side of the outgoing radiation of said electroluminescent element, or being a value near it.

[Claim 5] Said electroluminescent element is a field emitter according to claim 1 characterized by being an organic electroluminescent element.

[Claim 6] The liquid crystal display characterized by consisting of a liquid crystal display component and a field emitter according to claim 1 arranged back [the].

DETAILED DESCRIPTION

[Detailed Description of the Invention] [0001]

[Field of the Invention] This invention relates to the liquid crystal display which uses the field emitter and it which used the electroluminescent element (henceforth an EL element).

[0002]

[Description of the Prior Art] The EL element used as a field illuminant is used for the back light of the liquid crystal display component in a liquid crystal display etc. Drawing 7 is the sectional view which omitted hatching of the conventional EL element, and shows what is called an organic EL device here. This organic EL device makes the electroluminescence layer 4 which consists of an organic material intervene

transparent outgoing between the radiation lateral electrode 2 formed in one field of the transparence substrate 1 which consists of glass, and this outgoing radiation lateral electrode 2 and the background electrode 3 which counters, and said outgoing radiation lateral electrode 2 is used as an anode, and let the background electrode 3 be a cathode. [0003]In addition, said outgoing radiation lateral electrode 2 consists of ITO (indium stannic acid ghost), or an indium and a zincic acid ghost, and has high permeability to the light wavelength region. Said background electrode 3 is formed from a viewpoint of the electron injection to the electroluminescence layer 4 with Mg system alloys (a Mg-In alloy or Mg-Ag alloy) with a small work function. [0004]Moreover, although said electroluminescence layer 4 was shown as one layer by a diagram, generally this electroluminescence layer 4 is made into the two-layer structure which carried out the laminating of the electron hole transportation layer to the anode side of an electronic transportability luminous layer, or 3 layer structures which carried out the laminating of the electron hole transportation layer to the anode side on both sides of the luminous layer, and carried out the laminating of the electronic transportation layer to the cathode side.

[0005] If this organic EL device impresses an electrical potential difference (direct

current voltage) between that outgoing radiation lateral 2 electrode and background electrode 3, a luminescence drive is carried out and an electrical potential difference is impressed between these two electrodes 2 and 3, an electron is injected into the electroluminescence layer 4 for an electron hole from the background electrode (cathode) 3 from the outgoing radiation lateral electrode (anode) 2, a singlet exciton will occur by the recombination of that electron hole and electron that were poured in, and it will emit light.

[0006] And incidence of the light by this singlet exciton is carried out to the outgoing radiation lateral electrode 2 from the electroluminescence layer 4, and it penetrates the transparence substrate 1 further and it carries out outgoing radiation to that front face. In addition, although there is also light which goes to side of the rear-face the electroluminescence layer 4 among the light which said singlet exciton emits, the light is reflected with the background electrode 3.

[0007] Although the light from this point will be emitted toward various directions as an arrow shows to drawing 7 if the outgoing radiation path of the light from one point of the electroluminescence layer 4 in the above mentioned EL element is seen Among those, the light which goes in the direction (direction in alignment with the perpendicular to an outgoing

radiation side) perpendicular to an outgoing radiation side (front face of a substrate 1) penetrates the interface of each class of an EL element, and the interface of said outgoing radiation side and open air, without producing refraction and reflection, and they carry out outgoing radiation perpendicularly.

[0008] On the other hand, in order to carry out incidence of the synchrotron orbital radiation which goes in the direction of slant to the interface of said each class aslant, the light is refracted or reflected by said interface. The refractive index of the air this | whose | the refractive indexes of about 2.00 and the transparence substrate (glass) 1 are 1.45-1.80 in the case where the refractive index by the side of the outgoing radiation of the electroluminescence layer 4, for example, the refractive index of the electron hole transportation layer in the electroluminescence layer of 3 layer structures, is I the refractive index of 1.40-1.80, and the outgoing radiation lateral electrode 2 J ITO, and is the open air is about 1.0008, and is because the refractive indexes of an adjacent layer differ mutually.

[0009] For this reason, total reflection of the light which the light which carried out incidence of the synchrotron orbital radiation which goes in said direction of slant to the interface A of the electroluminescence layer 4 and the outgoing radiation lateral electrode 2

first, and carried out incidence by the incident angle smaller than a total reflection critical angle to said interface A among that light was refracted by this interface A, carried out incidence to the outgoing radiation lateral electrode 2, and carried out incidence by the larger incident angle than a total reflection critical angle is carried out by said interface A.

[0010] In addition, the light which carried out total reflection by said interface A repeats reflection with the background electrode 3, and reflection by said interface A and the end face of the of the longitudinal direction electroluminescence layer 4, and the light which it refracts and progresses to zigzag, is that process, and carried out incidence of the inside of the electroluminescence layer 4 to said interface A by the incident angle smaller than a total reflection critical angle penetrates this interface A, and carries out incidence of it to the outgoing radiation lateral electrode 2.

[0011] Moreover, total reflection of the light which the light which the light which the light which carried out incidence to the outgoing radiation lateral electrode 2 penetrated this outgoing radiation lateral electrode 2, carried out incidence to the interface B with the transparence substrate 1, and carried out incidence by the incident angle smaller than a total reflection critical angle to said interface B among that light was refracted by this

interface B, carried out incidence to the transparence substrate 1, and carried out incidence by the larger incident angle than a total reflection critical angle is carried out by Interface B.

[0012] A part of light of the light which carried out total reflection by this interface B repeats the total reflection in A with the interface the electroluminescence layer 4, and reflection by said interface B and the end face of the longitudinal direction of the outgoing radiation lateral electrode 2, and the light which refracted and progressed to zigzag and carried out incidence of the inside of the outgoing radiation lateral electrode 2 to said interface B by the incident angle smaller than a total reflection critical angle light penetrates that this interface B, and carries out incidence of them to the transparence substrate 1.

[0013] Moreover, although other light which carried out total reflection by said interface B penetrates the interface A with said electroluminescence layer 4 and returns to the electroluminescence layer 4 The light refracts and progresses the inside of the electroluminescence layer 4 above-mentioned by the zigzag interface A like the light which carried out total reflection, and is the process. The light which the light which carried out incidence to said interface A by the incident angle smaller than a total reflection critical angle penetrated this interface A, carried out incidence to the outgoing radiation lateral electrode 2, and carried out incidence to the interface B with the outgoing radiation lateral electrode 2 of them by the incident angle smaller than a total reflection critical angle penetrates this interface B, and carries out incidence to the transparence substrate 1.

[0014] Furthermore, total reflection of the light in which the light which the light which carried out incidence to the transparence substrate 1 from the outgoing radiation lateral electrode 2 penetrated this transparence substrate 1, carried out incidence to the interface C of that front face and open air (air), and carried out incidence by the incident angle smaller than a total reflection critical angle to said interface C among that light refracted for which and carried out outgoing radiation by this interface C and which carried out incidence by the larger incident angle than a total reflection critical angle is carried out by said interface C.

[0015] A part of light of the light which carried out total reflection by this interface C repeats the total reflection in the interface B with the outgoing radiation lateral electrode 2, and reflection by said interface A and the end face of the longitudinal direction of the transparence substrate 1, and the light which refracted and progressed to zigzag and carried out incidence of the inside of

the transparence substrate 1 among that light by the incident angle smaller than a total reflection critical angle to said interface C penetrates this interface C, and they carries out outgoing radiation.

[0016] Moreover, although other light which carried out total reflection by said interface C penetrates the interface B with said outgoing radiation lateral electrode 2, returns to the outgoing 2, radiation lateral electrode or penetrates the interface A with the electroluminescence layer 4 further and returns to the electroluminescence layer The light which refracted progressed the inside of the outgoing radiation lateral electrode 2 or the electroluminescence layer 4 to zigzag, and carried out incidence to interfaces A and B of them by the incident angle smaller than a total reflection critical angle carries out incidence of the light to the transparence substrate 1 again as mentioned above. The light which carried out incidence by the incident angle smaller than a total reflection critical angle to the interface C with said open air among the light carries out outgoing radiation.

[0017] That is, in the above mentioned EL element, incidence is carried out by the incident angle smaller than a total reflection critical angle to the interface A of the electroluminescence layer 4 and the outgoing radiation lateral electrode 2, and the interface B of the outgoing

radiation lateral electrode 2 and the transparence substrate 1, these interfaces A and B are penetrated, and the light which carried out incidence by the incident angle smaller than a total reflection critical angle to the interface C of the front face of said transparence substrate 1 and the open air which are an outgoing radiation side further turns into outgoing radiation light.

[0018] In addition, although it progresses while such light is refracted in the electroluminescence layer 4, the outgoing radiation lateral electrode 2, and the transparence substrate 1 as mentioned above although total reflection of other light is carried out in either of the field sides A, B, and C, it is the process, and a part of light carries out outgoing radiation from the end face of said outgoing radiation lateral electrode 2, and the electroluminescence layer 4 and the transparence substrate 1, and turns into leakage light.

[0019] Therefore, the light which finally carries out outgoing radiation to an outgoing radiation side As it is the light which carries out incidence by the incident angle smaller than a total reflection critical angle to the interface C of an outgoing radiation side and the open air and is shown in drawing 7 The include angle to the perpendicular direction (direction in alignment with the perpendicular to an outgoing radiation side) in the interface A with the outgoing

radiation lateral electrode 2 of the light which light the emitted in electroluminescence layer 4 The incident angle alpha If an include angle | as opposed to said perpendicular direction from the incident angle gamma and an outgoing radiation side for an include angle / as opposed to said perpendicular direction in the interface C of the incident angle beta, the transparence substrate 1, and the open air for the include angle to said perpendicular direction in the interface of the outgoing radiation lateral 2 and the transparence electrode substrate 1] is used as the outgoing radiation angle delta Finally the light of the range smaller than 90 degrees is a light which carries out incidence by the following incident angles alpha, beta, and gamma to said interfaces A, B, and C of the light in which the light delta which carries out outgoing radiation from an outgoing radiation side, i.e., an outgoing radiation angle, emitted light in the electroluminescence layer 4.

[0020] If the refractive index of the air which is [refractive index / of the electroluminescence layer 4] 1.45 and the open air about the refractive index of 2.00 and the transparence substrate 1 in the refractive index of 1.60 and the outgoing radiation lateral electrode 2 is set to 1.0008 here The incident angles alpha, beta, and gamma to the field sides A, B, and C where the outgoing radiation angle delta becomes delta<=90 degrees are

alpha<=38.7 degrees beta<=30.0 degrees gamma<=43.6 degrees, and a light smaller than 43.6 degrees turns into [the incident angle gamma over an outgoing radiation side] outgoing radiation light among the light which carries out incidence to an outgoing radiation side (the interface C of the front face of the transparence substrate 1, and the open air).

[0021]

Solved by the [Problem(s) be to although Invention] the However, brightness of the light (light of delta= 0 degree of outgoing radiation angles) which carries out outgoing radiation of the above-mentioned conventional EL element in the direction of a transverse plane, i.e., the direction perpendicular to an outgoing radiation side, is high, since the brightness falls rapidly in connection with the outgoing radiation angle delta becoming large, The outgoing radiation angle range where the luminance distribution of outgoing radiation light is strong directive distribution, therefore the outgoing radiation light of high brightness is obtained has the problem of being narrow.

[0022] And although the EL element is used for the back light of the liquid crystal display component in a liquid crystal display etc. The liquid crystal display with which the above mentioned conventional EL element uses this EL element as said back light since the

luminance distribution of that outgoing radiation light is strong directive distribution If the display is observed from across to a direction perpendicular to an outgoing radiation side, since a screen will become quite dark, the include angle range which can observe a display with sufficient brightness has the problem of being narrow.

[0023] Then, now, although it considers diffusing the outgoing radiation light of an EL element with a diffusion plate, and distribution making luminance outgoing radiation light into homogeneity mostly from the former, since the outgoing radiation light of the outgoing radiation angle range of high brightness of an EL element is also diffused and the brightness falls, the brightness of the light which carries out outgoing radiation in the predetermined direction (for example, the direction of a transverse plane) cannot be made high.

[0024] This invention is united and aims at offering the liquid crystal display using that field emitter while it offers what can make high the brightness of the light which carries out outgoing radiation in the predetermined direction as a field emitter which used the EL element, can make large the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained, and can improve the luminance distribution of outgoing radiation light. [0025]

[Means for Solving the Problem] The field emitter of this invention is characterized by preparing luminance distribution control-section material with the property which the light which the light which carried out incidence toward the predetermined direction among incident light from the rear face which counters that outgoing radiation side went straight on, carried out [light] outgoing radiation to the front face, and carried out incidence toward other directions is scattered on the outgoing radiation side of an EL element, and carries out outgoing radiation to said front face.

[0026] Namely, the field emitter of this invention is made to carry out outgoing radiation of the light which emits light in an EL element and carries out outgoing radiation to that front face through said luminance distribution control-section material, and according to this field emitter In order to scatter about the light which the light which carried out incidence toward the predetermined direction among the light which carried out outgoing radiation of said EL element, and carried out incidence to luminance distribution control-section material from the rear face went straight on, carried out outgoing radiation to the front face, and carried out incidence toward other directions and to carry out outgoing \mathbf{front} said radiation to face, brightness of the outgoing radiation light

to said predetermined direction can be made high, the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained can be made large, and the distribution of outgoing luminance radiation light can be improved. [0027] The liquid crystal display of this invention arranges said field emitter as that back light behind a liquid crystal display component. Moreover, this field emitter Since the outgoing radiation angle range where the outgoing radiation light of brightness with the brightness of the outgoing radiation light predetermined direction sufficient high moreover is obtained is wide, According to this liquid crystal display, the fall of the brightness of the screen when observing that display from across can be lessened, and the include angle range which can observe a display with sufficient brightness can be made large. [0028]

[Embodiment of the Invention] The inside of the incident light from the rear face where the field emitter of this invention counters the outgoing radiation side of an EL element as mentioned above in that outgoing radiation side, By preparing luminance distribution control-section material with the property which the light which the light which carried out incidence toward the predetermined direction went straight on, carried out [light] outgoing radiation to the front

face, and carried out incidence toward other directions is scattered about, and carries out outgoing radiation to said front face The brightness of the outgoing radiation light to a predetermined direction is made high, the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained is made large, and the luminance distribution of outgoing radiation light is improved.

[0029] In the field emitter of this invention said luminance distribution control-section material It consists of scatter reflection film inserted between the side faces of two or more area pellucida located in a line along the direction of a field, and these area pellucida. If the thing on the field where said scatter reflection film met in said predetermined direction is desirable and distribution considers luminance control-section material such a as configuration The light which carried out incidence to said area pellucida toward the predetermined direction among the light which carries out incidence from the rear face can be made to be able to go straight on, and the light which carried out incidence toward other directions can be scattered about with said scatter reflection film.

[0030] Moreover, as for said luminance distribution control-section material, it is desirable to stick the rear face to the outgoing radiation side of an EL element,

and to prepare it, the refractive index of said area pellucida is almost the same as the refractive index by the side of the outgoing radiation of said EL element, or it is still more desirable that it is a value near it.

[0031] Thus, while the rear face of said brightness distribution control member has stuck to the outgoing radiation side of an EL element, the refractive index of said area pellucida is almost the same as the refractive index by the side of the outgoing radiation of an EL element, or if it is a value near it, since the light which carried out outgoing radiation will carry out incidence of the EL element to a brightness distribution control member efficiently, outgoing radiation of the light which emitted light in the EL element can be carried out at high effectiveness, and the outgoing radiation light of high brightness can be obtained.

loo32] Moreover, although an organic EL device is sufficient as said EL element, and depression of partial brightness arises in the luminance distribution of the outgoing radiation light from an EL element corresponding to the generating part of said dark spot when a dark spot peculiar to an organic EL device occurs in that case Since the light which carries out outgoing radiation to the front face of said brightness distribution control member turns into light of luminance distribution which had depression of said brightness canceled by dispersion, even if

a dark spot occurs in an EL element, it can carry out outgoing radiation of the light of good luminance distribution without depression of partial brightness. [0033] Especially this is effective in the liquid crystal display which uses said field illuminant as a back light, and since according to this liquid crystal display the light of luminance distribution which had depression of brightness canceled carries out incidence to a liquid crystal display component even if a dark spot occurs in the EL element of said field illuminant, it can display the image of high quality without the brightness fall of the pixel corresponding to the generating part of said dark spot.

[0034]

[Example] <u>Drawing 1</u> is the sectional view which omitted hatching of the field illuminant by the 1st example of this invention. This field emitter forms the luminance distribution control-section material 20 which had the property which the light which the light which incidence the carried out toward predetermined direction among incident light from the rear face which counters that outgoing radiation side went straight on, carried out [light] outgoing radiation to the front face, and carried out incidence toward other directions is scattered about, and carries out outgoing radiation to said front face in the outgoing radiation side of EL element 10.

[0035] First, if EL element 10 is explained, this EL element body 10 is the organic EL device which made the electroluminescence layer 14 which consists of an organic material intervene between the transparent outgoing radiation lateral electrode 12 formed in one field of the transparence substrate 11 which consists of glass, and this outgoing radiation lateral electrode 12 and the background electrode 13 which counters, and that outgoing radiation lateral electrode 12 is used as an anode, and let the background electrode 13 be a cathode. [0036]addition. outgoing In said radiation lateral electrode 12 consists of ITO, or an indium and a zincic acid ghost, and said background electrode 13 is formed with Mg system alloys, such as a Mg-In alloy or a Mg-Ag alloy with a small work function.

[0037] However, since said Mg system alloy has high reactivity, it has a possibility of the background electrode 13 which consists of this Mg system alloy reacting with the moisture in air, and deteriorating, or reacting with oxygen and oxidizing.

[0038] Therefore, in this example, as shown in <u>drawing 1</u>, the perimeter of said EL element 10 was covered with the airtight high resin film 15 over the inferior surface of tongue of the transparence substrate 11 from that whole rear face, and the background electrode 13 which consists of said Mg

system alloy is completely covered from air.

[0039] Moreover, although drawing 1 showed said electroluminescence layer 14 as one layer, this electroluminescence layer 14 has 3 layer structures which carried out the laminating of the electron hole transportation layer to the anode side on both sides of the two-layer which carried the out structure the hole of electron laminating transportation layer to the anode side of an electronic transportability luminous layer, or a luminous layer, and carried out \mathbf{of} the electronic the laminating transportation layer to the cathode side. When making [0040]

electroluminescence layer 14 into 3 layer structures, for example, in addition, a luminous layer DPVBi {a 4 and 4'-screw (2 and 2-diphenyl vinylene) biphenyl} and BCz VBi {a 4 and 4'-screw (2-carbazole vinylene) biphenyl} It forms by the polymeric materials which mixed DPVBi 96% of the weight, and mixed BCz VBi at 4% of the weight of a rate. An electron hole transportation layer It forms by alpha-NPD {N, N'-JI (alpha-naphthyl)-N, -1 and N'-diphenyl and 1'-biphenyl-4,4'-diamine}, and an electronic transportation layer is formed by Alq3 {tris(8-hydroxyquinoline)-ized aluminum}.

[0041] The refractive indexes of the layer by the side of the outgoing radiation of said electroluminescence layer 14, i.e., the refractive index of the electron hole transportation layer which consists of alpha-NPD, are 1.40-1.80, and, in the case of ITO, the refractive indexes of about 2.00 and the transparence substrate (glass) 1 of the refractive index of the outgoing radiation lateral electrode 12 are 1.45-1.80.

[0042] If this EL element 10 impresses an electrical potential difference (direct current voltage) between that outgoing radiation lateral electrode 12 and background electrode 13, a luminescence drive is carried out and an electrical potential difference is impressed between these two electrodes 12 and 13, an the is injected into electron electroluminescence layer 14 for an electron hole from the background electrode (cathode) 13 from the outgoing radiation lateral electrode (anode) 12, a singlet exciton will occur by the recombination of that electron hole and electron that were poured in, and it will emit light.

[0043] And incidence of the light by this singlet exciton is carried out to the outgoing radiation lateral electrode 12 from the electroluminescence layer 14, and it penetrates the transparence substrate 11 further and it carries out outgoing radiation to that front face. In addition, although there is also light which goes to the rear-face side of the electroluminescence layer 14 among the light which said singlet exciton emits, the

light is reflected with the background electrode 13.

[0044] In addition, the luminous layer which said electroluminescence layer 14 turns into from Above DPVBi and BCz VBi, When it is 3 layer structures which carried out the laminating of the electron hole transportation layer which consists and the electronic alpha·NPD, of transportation layer which consists of Alq3, the light which emits light in this electroluminescence layer 14 Although all the wavelength of a light band is included, it is the light of a wavelength component with much [a little] quantity of light of the wavelength region of the blue of them, therefore the luminescent color turns into a color which wore blueness.

[0045] Then, he is trying to bring the color of the light which carries out outgoing radiation of said EL element 10 close to white in this example by distributing a red fluorescent material fluorescent material and a green optimum making said dose every, fluorescent material absorb a part of light which emitted light, and generating green fluorescence with red in the of said luminous layer electroluminescence layer 14, or the electron hole transportation layer by the side of outgoing radiation.

[0046] Next, the above mentioned luminance distribution control section material 20 is explained. <u>Drawing 2</u> is the perspective view of said brightness

distribution control member 20. This luminance distribution control-section material 20 consists of a film which was inserted between two or more area pellucida 21 located in a line along that direction of a field, and the side face of these area pellucida 21 and which each both sides come out and consists of a certain scatter reflection film 22, and said scatter reflection film 22 is on the field which met in the predetermined direction. Hereafter, this luminance distribution control-section material 20 is called luminance distribution control film.

[0047] In addition, the diffusibility film which consists of a sintered compact of metallic oxides, such as reflexibility microcrystal film, such as inorganic metals, such as aluminum or silver, and organic metal containing an polyacethylene derivative, and titanium oxide, a zinc oxide, an aluminum oxide, a as said scatter magnesium oxide, reflection film 22 is used.

[0048] This luminance distribution control film 20 is on the field where said scatter reflection film 22 met in the direction perpendicular to a film plane, and this luminance distribution control film 20 is making the shape of a louver mutually located in a line in parallel at spacing at which the straight-line-like scatter reflection film 22 which met one of crosswise [those / in every direction] is equivalent to the width of face of said area pellucida 21.

addition. luminance [0049]the In distribution control film 20 of the shape of this louver carries out the laminating of the transparent resin layer and said scatter reflection film 22 of the thickness equivalent to the width of face of said area pellucida 21 by turns, and can manufacture them by the approach of slicing that laminating Grock in the shape of a film along with a cutting plane perpendicular to the thickness direction (the direction of a laminating).

[0050] Moreover, the refractive index of the area pellucida 21 of said luminance distribution control film 20 is almost the same as the refractive index by the side of ofradiation outgoing the above-mentioned EL element 10 (this of index refractive example transparence substrate 11), or it consists of transparence resin which is a value near it.

the addition, although [0051]In refractive indexes by the side of the outgoing radiation of EL element 10, i.e., the refractive index of the transparence substrate 11 which consists of glass, are 1.45-1.80, it is almost the same as it, or as transparence resin with the refractive index of a near value, there are PET **PES** terephthalate), (polyethylene PC phon), (polyether ape a (polycarbonate), etc., and the refractive indexes of these resin are 1.40-1.60.

[0052] And said luminance distribution control film 20 makes the outgoing

element 10 stick a film rear face to the outgoing radiation side (front face of the transparence substrate 11) of EL element 10, and is prepared in it. In addition, in this example, it is almost the same as one of the refractive index of that area pellucida 21, and the refractive indexes of the transparence substrate 11 of EL element 10 in the brightness distribution control film 20, or EL element 10 is pasted with transparence adhesives (not shown) with the refractive indexes.

[0053] The above mentioned field emitter is made to carry out outgoing radiation of the light which emits light in the electroluminescence layer 14 of EL element 10, and carries out outgoing radiation to the front face of EL element 10 through said luminance distribution control film 20.

[0054] First, although the light from this point will emit it toward various directions as an arrow shows to drawing 1 if the outgoing radiation path on the front face of an EL element of the light in the which emitted light electroluminescence layer 14 of EL element 10 is seen about the light from one point of said electroluminescence layer 14 Among those, the light which goes in the direction (direction in alignment with the perpendicular to an outgoing radiation side) perpendicular to the outgoing radiation side of EL element 10 Interface A' of the electroluminescence layer 14 and the outgoing radiation lateral electrode 12 and interface B' of said outgoing radiation lateral electrode 12 and transparence substrate 11 are penetrated without producing refraction and reflection, and carry out outgoing radiation at right angles to an EL element front face.

[0055] On the other hand, although incidence of the synchrotron orbital radiation which goes in the direction of slant is aslant carried out to said field side A' and B', since the refractive indexes of the layer which the refractive index of said electroluminescence layer radiation 14 and outgoing lateral 12, and the transparence electrode substrate 11 is the value which was mentioned above, and adjoins each other differ mutually, the synchrotron orbital radiation which goes in said direction of slant is refracted or reflected by said field side A' and B'.

[0056] That is, total reflection of the light which the light which carried out incidence of the synchrotron orbital radiation which goes in the direction of A' of the slant to interface electroluminescence layer 14 and the outgoing radiation lateral electrode 12 first, and carried out incidence by the incident angle smaller than a total reflection critical angle to said interface A' among that light was refracted by this interface A', carried out incidence into the

outgoing radiation lateral electrode 12, and carried out incidence by the larger incident angle than a total reflection critical angle is carried out by said interface A'.

[0057] In addition, while being reflected with the background electrode 13, it reflects by the end face of said interface A' and the electroluminescence layer 14, and the light which it refracts and progresses to zigzag, is that process, and carried out incidence of the inside of the electroluminescence layer 14 to said interface A' by the incident angle smaller than a total reflection critical angle penetrates this interface A', and carries out incidence of the light which carried out total reflection by said interface A' into the outgoing radiation lateral electrode 2.

[0058] Moreover, total reflection of the light which the light which the light which carried out incidence to the outgoing radiation lateral electrode 12 penetrated the inside of this outgoing radiation lateral electrode 12, carried out incidence to interface B' with the transparence substrate 11, and carried out incidence by the incident angle smaller than a total reflection critical angle to said interface B' among that light was refracted by this interface B', the carried incidence into out transparence substrate 11, and carried out incidence by the larger incident angle than a total reflection critical angle is carried out by interface B'.

[0059] A part of light of the light which carried out total reflection by this interface B' repeats reflection by the end face of the longitudinal direction of the total reflection in interface A' with the 14, said electroluminescence layer interface B', and the outgoing radiation lateral electrode 12, and the light which refracted and progressed to zigzag and carried out incidence of the inside of the outgoing radiation lateral electrode 12 to said interface B' by the incident angle smaller than a total reflection critical angle among that light penetrates this interface B', and carries out incidence of them to the transparence substrate 11. [0060] Moreover, although other light which carried out total reflection by said interface B' penetrates interface A' with said electroluminescence layer 14 and returns to the electroluminescence layer 14 The light refracts and progresses the inside of the electroluminescence layer 14 to zigzag by above mentioned interface A' like the light which carried out total reflection, and is the process. The light which the light which carried out incidence to said interface A' by the incident angle smaller than a total reflection critical angle penetrated this interface A', carried out incidence to the outgoing radiation lateral electrode 2, and carried out incidence to interface B' with the outgoing radiation lateral electrode 2 of them by the incident angle

smaller than a total reflection critical angle penetrates this interface B', and carries out incidence to the transparence substrate 11.

[0061] And the light which carried out incidence to the transparence substrate 11 from the outgoing radiation lateral electrode 12 penetrates this transparence substrate 11, it carries out outgoing radiation to that front face, and it carries out incidence to the area pellucida 21 of the above mentioned luminance distribution control film 20 from that rear face.

[0062] In this case, while making into the value near it whether to be almost the same as the refractive index by the side of the outgoing radiation of EL element 10 (refractive index of the transparence substrate 11) in the refractive index of the area pellucida 21 of said luminance distribution control film 20 in this example This luminance distribution control film 20 [whether it is almost the same as one of the refractive index of that area pellucida 21, and the refractive indexes of the transparence substrate 11 of EL element 10, and J Or since EL the 10 pasted with element adhesives with the transparence refractive index between both refractive indexes which are not illustrated, No matter the incident angle may be what include angle, without the most carrying out total reflection, the light which carried out incidence to interface C' of the

front face of EL element 10 and the luminance distribution control film 20 penetrates said interface C', and it carries out incidence to the area pellucida 21 of the luminance distribution control film 20.

[0063] Next, if the outgoing radiation path of the light which carried out incidence to the area pellucida 21 of said luminance distribution control film 20 is explained The direction which met the scatter reflection film 22 among the light which carried out incidence to this area pellucida 21 from that rear face, That is, the light (light which carried out outgoing radiation perpendicularly from element 10) which carried out incidence toward the direction perpendicular to the film plane of the luminance distribution control film 20 goes straight on, and carries out outgoing radiation of said area pellucida 21 at right angles to the front face of the luminance distribution control film 20.

[0064] On the other hand, the light which carried out incidence to said area pellucida 21 toward other directions, i.e., the light which carried out incidence aslant to the film plane of the luminance distribution control film 20, penetrates the area pellucida 21 aslant, it carries out incidence to the scatter reflection film 22 of the side face, and they is scattered about in the dispersion reflector.

[0065] In addition, the light which arrives at the front face of the area pellucida 21

as it is, without carrying out incidence to said scatter reflection film 22 is also in the light which penetrates said area pellucida 21 aslant, and outgoing radiation of the light is carried out to the front face of the luminance distribution control film 20, without being scattered about. In interface D' of the front face of the area pellucida 21, and the open air, this outgoing radiation light is refracted the refractive-index according to difference of the incident angle over this interface D', and said area pellucida 21 and open air (air), and carries out outgoing radiation in that direction.

[0066] The light scattered about by said scatter reflection film 22 progresses the inside of the area pellucida 21 toward various directions, and the light which goes to the front face of the area pellucida 21 of them carries out incidence to interface D' with said open air.

[0067] In addition, the most carries out incidence of the light which carried out incidence to said area pellucida 21 in order that the light which most of the light carries out incidence to the scatter reflection film 22 of the opposite side although incidence of the light which goes in other directions is not directly carried out to said interface D', and is scattered about again, and goes to the front face of the area pellucida 21 of the scattered light might carry out incidence to said interface D' to said interface D'.

[0068] And the light which carried out

incidence to interface D' of the front face of said area pellucida 21 and the open air by the incident angle smaller than a total reflection critical angle to said interface D' among the light which carried out incidence penetrates this interface D', and it carries out outgoing radiation to front face \mathbf{of} \mathbf{the} luminance the distribution control film 20. In said interface D', this outgoing radiation light refracted according the to is refractive index difference of the incident angle over this interface D', and said area pellucida 21 and open air (air), and carries out outgoing radiation in that direction.

[0069] Moreover, although total reflection of the light which carried out incidence to said interface D' by the larger incident angle than a total reflection critical angle is carried out by this interface D', since incidence of it is carried out to the scatter reflection film 22 of that reflective direction and it is scattered about again, finally incidence of that light is carried out to said interface D' by the incident angle smaller than a total reflection critical angle, such light also penetrates this interface D' and it carries out outgoing radiation to the front face of the luminance distribution control film 20.

[0070] Thus, the inside of the light which according to the above mentioned field emitter carried out outgoing radiation of EL element 10, and carried out incidence to the luminance distribution control film

20 from the rear face, In order to scatter about the light which the light which out incidence carried toward perpendicular direction went straight on, carried out outgoing radiation to the front face, and carried out incidence toward other directions and to carry out outgoing radiation to said front face, The brightness of the outgoing radiation light to said perpendicular direction can be made high, the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained can be made large, and the outgoing of distribution luminance radiation light can be improved.

[0071] In addition, the light which carries out incidence at right angles to interface D' of the front face of said luminance distribution control film 20 and the open air is also in the light scattered about in the luminance distribution control film 20, and in order to carry out outgoing radiation of the light perpendicularly, without being refracted by said interface D', the brightness of the outgoing radiation light to said perpendicular direction becomes still higher than the brightness of the rectilinear propagation light which penetrates the luminance 20 film control distribution perpendicularly, and carries out outgoing radiation to a front face.

[0072] And the inside of the light which according to the above-mentioned field emitter carried out outgoing radiation of

EL element 10, and carried out incidence to each area pellucida 21 of the luminance distribution control film 20, The light which progresses by the larger incident angle than a total reflection critical angle toward interface D' of the front face of said area pellucida 21 and the open air which are a final outgoing radiation side is scattered about, and a direction is changed. Since that light carries out incidence to said interface D' by the incident angle smaller than a total reflection critical angle and outgoing this interface \mathbf{D} ' \mathbf{of} radiation penetrated and carried out, outgoing radiation effectiveness of the light which carried out incidence to the brightness distribution control film 20 from EL element 10 can be made high.

[0073] In furthermore, the process which progresses while the light which carried out total reflection in respect of [A, B and C] each field is refracted in the EL the element in conventional electroluminescence layer 4, the outgoing radiation lateral electrode 2, and the transparence substrate 1, as shown in drawing 7 Although the loss of the light in a process until it carries out outgoing radiation of the EL element is large, therefore the outgoing radiation quantity of light decreases considerably compared with the luminescence energy in the electroluminescence layer 4 since a part of the light carries out outgoing radiation from the end face of said outgoing

radiation lateral electrode 2, and the electroluminescence layer 4 and the transparence substrate 1 and turns into leakage light According to the above mentioned field emitter, there are also few losses of the light in a process until it carries out outgoing radiation of EL element 10.

[0074] Namely, although a part of the light carries out outgoing radiation from the end face of said outgoing radiation 2, electrode and the lateral electroluminescence layer 4 and the transparence substrate 1 and turns into leakage light also in the above mentioned field emitter in the process which progresses while the light which carried out total reflection by interface A' and B' is refracted in the electroluminescence layer 14 and the outgoing radiation lateral electrode 12 as shown in drawing 1 As mentioned above, no matter the incident angle over interface C' of the transparence substrate 11 and the luminance distribution control film 20 may be what include angle, the light which carried out incidence to the transparence substrate 11 In order to penetrate said interface C' and to carry out incidence to the area pellucida 21 of the luminance distribution control film 20, without the most carrying out total reflection, the leakage light from the end face of a transparence substrate like the conventional EL element is hardly produced.

[0075]Therefore, according to the above-mentioned field light emitting device, the quantity of light which carries out outgoing radiation of EL element 10, and penetrates and carries out outgoing radiation of the brightness distribution control film 20 further can be made [many] by leaps and bounds compared with the outgoing radiation quantity of light of the conventional EL element (more than twice [at least]), and the outgoing radiation light of high brightness can be obtained.

[0076] <u>Drawing 3</u> is drawing showing the luminance distribution of the outgoing radiation light of the above mentioned field the emitter in luminance distribution of the conventional EL element, and the outgoing radiation side of the EL element as compared with distribution when the luminance diffusion plate has been arranged, and the continuous line shows luminance when the luminance distribution distribution of the field emitter of the above-mentioned example, the luminance distribution of the EL element of the former [broken line], and an alternate long and short dash line have arranged the diffusion plate to the outgoing radiation side of the conventional EL element.

[0077] In addition, the luminance distribution of the above mentioned field emitter shown in <u>drawing 3</u> It is perpendicular to the outgoing radiation

(front face of the luminance distribution control film 20) of a field and the luminance emitter, are distribution on the field which met in the intersects which direction perpendicularly to the area pellucida 21 of the luminance distribution control film 20, and the die-length direction of the scatter reflection film 22, and it sets to drawing. + The outgoing radiation angle of the light which carries out outgoing radiation of theta in one direction to a direction (the direction of theta= 0 degree angles) \mathbf{of} outgoing radiation perpendicular to an outgoing radiation side, and theta are the outgoing radiation angles of the light which carries out outgoing radiation to an opposite direction to said perpendicular direction. [0078] Like this <u>drawing 3</u>, although the brightness of the light which carries out outgoing radiation of the luminance distribution of the conventional EL element in the direction of a transverse plane (direction perpendicular to an outgoing radiation side) is high, the outgoing radiation angle range to which that brightness falls rapidly in connection with outgoing radiation angle becoming large and where it is strong distribution. directive therefore the of light high outgoing radiation brightness is obtained is narrow.

[0079] Moreover, although it is almost uniform distribution, since luminance distribution when the diffusion plate has been arranged to the outgoing radiation side of the conventional EL element also diffuses the outgoing radiation light of the outgoing radiation angle range of high brightness of an EL element, the brightness of the light which carries out outgoing radiation in the direction of a transverse plane is quite low [luminance distribution] compared with the conventional EL element.

The [0080] It compares with these. luminance distribution of the emitter of the above mentioned example The brightness of the outgoing radiation light to the direction of a transverse plane is distribution with the wide outgoing radiation angle range where the outgoing radiation light of sufficient brightness is obtained high moreover. And in order to carry out outgoing radiation also of the light which carried out incidence at right angles to interface D' with the open air of the light scattered about in said luminance distribution control film 20 perpendicularly besides the rectilinear propagation light which penetrates the luminance distribution control film 20 perpendicularly, and carries out outgoing radiation to a front face, The brightness of the light which carries out outgoing radiation in the direction of a transverse plane is still higher than the conventional EL element. [0081] Moreover, the organic EL device equipped with the electroluminescence layer 14 which consists of a conductive polymer as the EL element 10 is used for the field emitter of the above mentioned example, and since the permeability of an organic EL device of the light of the electroluminescence layer 14 is high, it can carry out outgoing radiation of the light which emitted light efficiently.

[0082] Moreover, since, as for said organic EL device, the electroluminescence layer 14 consists of an organic material, If the poor luminescence part called a dark spot an interface with the outgoing radiation lateral electrode 12 which consists of this electroluminescence layer 14 and metallic material may occur and occurs Although dark spot this depression of partial brightness arises in luminance distribution of the outgoing radiation light from EL element 10 corresponding to the generating part of said dark spot The light which carries out outgoing radiation to the front face of said luminance distribution control film 20 Since it is the light of luminance distribution which had depression of said canceled by dispersion, brightness According to the above mentioned field emitter, even if a dark spot peculiar to an organic EL device occurs in EL element 10 Since it becomes the light of distribution which had luminance depression of brightness canceled, even if a dark spot occurs in EL element 10, outgoing radiation of the light of good distribution without luminance depression of partial brightness can be carried out.

[0083] <u>Drawing 4</u> is the sectional view which omitted hatching of the field illuminant by the 2nd example of this The field emitter of this invention. transparence example makes the substrate of EL element 10 serve a double purpose with the luminance distribution control film 20, and the fundamental structure of EL element 10 and the structure of the luminance distribution control film 20 are the same as the 1st example of the above.

[0084] However, in this example, a refractive index is almost the same as the refractive index by the side of the outgoing radiation of EL element 10 (refractive index of the electron hole transportation layer which is a layer by the side of that outgoing radiation when making the electroluminescence layer 14 into 3 layer structures), or forms the area of said luminance pellucida 21 distribution control film 20 by the transparence resin which is a value near it.

[0085] According to the field emitter of this example, no matter that incident angle may be what include angle, the light which carries out outgoing radiation of EL element 10, i.e., the light which carried out incidence to the interface of EL element 10 and the luminance distribution control film 20 In order to penetrate said interface and to carry out incidence to the area pellucida 21 of the

luminance distribution control film 20, without carrying out total reflection, The total reflection in the process in which the light which emitted light in the electroluminescence layer 14 of EL element 10 carries out outgoing radiation of EL element 10 The leakage of the light which only occurs in drawing 4 in the interface of the electroluminescence layer 14 and the outgoing radiation lateral electrode 12, therefore carried out total reflection of the outgoing radiation path to it as the arrow showed Since it becomes only leakage from the end face of the electroluminescence layer 14 mostly, the outgoing radiation quantity of light can be further made [many] rather than the 1st example of the above.

[0086] In addition, although the thing on the field where the scatter reflection film 22 met in the direction perpendicular to a film plane as a luminance distribution control film 20 was used in the 1st and 2nd examples of the above, the dispersion reflector of said scatter reflection film 22 may be an inclined plane.

[0087] The inside of the light which carried out outgoing radiation of the EL element, and carried out incidence to the luminance distribution control film from the rear face when using such a luminance distribution control film, In order to scatter about the light which the light which carried out incidence toward the direction which met the scatter reflection film 22 went straight on, and

carried out outgoing radiation to the front face and which carried out incidence toward other directions and to carry out outgoing radiation to said front face, The brightness of the outgoing radiation light to the direction of slant can be made high, the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained can be and the luminance large, made distribution of outgoing radiation light can be improved.

[0088] Moreover, although the thing which made the distributed condition contain the fluorescent material which emits red fluorescence to the luminous layer which emits a blue light as an electroluminescence layer 14, and the fluorescent material which emits green used in the fluorescence was above mentioned example The luminous layer of the shape of a dot which emits the light of not only this but red, the luminous layer of the shape of a dot which emits a green light, and the luminous layer of the shape of a dot which emits a blue light are arranged in by turns, are formed, and it may be made to make the color of the light which carries out outgoing radiation of EL element 10 into white.

[0089] Furthermore, although the brightness distribution control film 20 of the shape of a louver mutually located in a line in parallel at spacing at which the straight-line-like scatter reflection film

22 is equivalent to the width of face of the area pellucida 21 as a brightness distribution control member prepared in the outgoing radiation side of EL element 10 was used in the above mentioned example That from which what prepared the scatter reflection film in the shape of a grid into the transparent film prepared the scatter reflection film with short die length in the suitable pitch for the dip direction and the direction of breadth into the bright film is sufficient as said luminance distribution control-section material.

[0090] Drawing 5 is the perspective view showing the modification of a brightness distribution control member, and this brightness distribution control member makes the die length direction of two sheets and each scatter reflection film 22 intersect perpendicularly mutually, and piles up the louver-like brightness distribution control film 20 used in the above-mentioned example.

[0091] If such a brightness distribution control member is used, since the scatter reflection film 22 is formed in the shape of a grid and incident light is scattered about in the two directions which intersect perpendicularly mutually, luminance distribution of the outgoing radiation light of said two directions can be made distribution respectively like drawing 3.

[0092] In addition, the above-mentioned luminance distribution control-section

material should just have the property which the light which the light which carried out incidence toward the predetermined direction not only among what prepared the scatter reflection film into the transparent film but among the incident light from a rear face went straight on, carried out [light] outgoing radiation to the front face, and carried out incidence toward other directions is scattered about, and carries out outgoing radiation to said front face.

[0093] Next, the liquid crystal display using the above mentioned field emitter is explained. Drawing 6 is the side elevation showing one example of said liquid crystal display, and this liquid crystal display arranges the field emitter mentioned above as that back light 36 behind the liquid crystal display component 30.

[0094]The above mentioned crystal display component 30 is an ECB (birefringence effectiveness) mold liquid crystal display component of a simple matrix or an active matrix method, and it arranges polarizing plates 34 and 35 on the external surface of said substrates 31 and 32, respectively while it prepares the liquid crystal layer in which the liquid crystal molecule changed orientation into the predetermined orientation condition (for example, twist orientation condition) between the transparent electrode formation substrate 31 of a pair joined through the frame-like sealant 33, and 32. [0095] This ECB mold liquid crystal display component 30 is what obtains coloring light using a birefringence operation of a liquid crystal layer and the polarization of polarizing plates 34 and 35. Each wavelength light turns into light used as the elliptically polarized light from which a polarization condition differs, respectively according to a birefringence operation of liquid crystal in the process in which the linearly polarized light which penetrated and carried out incidence of one polarizing plate penetrates a liquid crystal layer, and the light carries out incidence to the polarizing plate of another side. The light which penetrated the polarizing plate of this another side turns into coloring light of a color according to the ratio of the optical reinforcement of each wavelength light which constitutes that light.

[0096] That is, since this ECB mold liquid crystal display component 30 obtains coloring light, without using a color filter and does not have the absorption of light according [therefore] to a color filter, it can make the permeability of light high and can obtain bright color display.

[0097] And the form birefringence of with the liquid changes crystal orientation conditions of the liquid according to the crystal molecule electrical potential difference on which the ECB mold liquid crystal display 30 component impressed to inter-electrode [of both the substrates 31

and 32]. Since the polarization condition of each wavelength light which carries out incidence to the polarizing plate of another side according to it changes, by controlling applied voltage, the color of coloring light can be changed, two or more colors by the same pixel can be displayed, and multicolor color pictures, such as a full color image, can be displayed.

[0098] Moreover, in this example, the field emitter of the 1st example shown in drawing 1 is used as said back light 36. Explanation of the configuration of this field emitter attaches and omits a same sign to drawing.

[0099] Since the field emitter with the wide outgoing radiation angle range where the outgoing radiation light of brightness with the brightness of the radiation light to outgoing a direction which was predetermined sufficient high above mentioned moreover is obtained as a back light 36 of that liquid crystal display component 30 is used for this liquid crystal display, it can lessen the fall of the brightness of the screen when observing that display from and can make large across, include angle range which can observe a display with sufficient brightness.

[0100] And since the above mentioned field emitter has much quantity of light which carries out outgoing radiation of EL element 10, and penetrates and carries out outgoing radiation of the

brightness distribution control film 20 further by leaps and bounds compared with the outgoing radiation quantity of light of the conventional EL element, it can carry out incidence of the light of high brightness to the liquid crystal display component 30, and can display the image of high brightness.

[0101]Moreover, since the above-mentioned liquid crystal display the above-mentioned field use can emitter for a back light 36 and can reflect light with the background electrode 13 of EL element 10 which is the source of luminescence of this field emitter, It is also possible to make it reflect in drawing 6 with the background electrode 13 of said EL element 10, and to display on it the outdoor daylight (natural light or indoor illumination light) which carries out incidence from the outgoing radiation side side of the liquid crystal display component 30, without carrying out the luminescence drive of said EL element 10, as a broken line shows. Therefore, it can be used as the so-called 2-way display which can perform both the transparency mold display using the light from a back light 36, and the reflective mold display using outdoor daylight.

[0102] In this case, since the field emitter of the above-mentioned example uses an organic EL device with the high permeability of the light of that electroluminescence layer 14 for EL element 10, when performing a reflective

mold display, it reflects efficiently the outdoor daylight which carried out incidence with the background electrode 13, and it not only can carry out outgoing radiation of the light which emitted light efficiently, but can obtain a bright display. [0103] Moreover, should make each of that scatter reflection film 22 correspond. respectively between the spacing of each pixel of the liquid crystal display component 30, and a train, and the luminance distribution control film 20 of said field emitter should be formed in the shape of a grid. If the black mask corresponding to the scatter reflection film 22 of the shape of said grid is prepared in said liquid crystal display component 30, while being able to prevent a flicker of the display by the light reflex of scatter reflection film 22 the very thing, incidence of the outgoing radiation light from EL element 10 can be efficiently carried out to each pixel of the liquid crystal display component 30.

[0104] In addition, although said EL element 10 may generate a dark spot peculiar to an organic EL device, even in such a case, the outgoing radiation light which carries (light out outgoing radiation to the front face of a brightness distribution control member) from a field emitter can carry out incidence of the light of the good luminance distribution which does not have depression of partial brightness since it becomes the light of luminance distribution which had depression of said brightness canceled by dispersion to the liquid crystal display component 30, and it can display the image of high quality.

[0105] And in this liquid crystal display, since the ECB mold liquid crystal display component which obtains coloring light as a liquid crystal display component 30, without using a color filter is used, a color picture bright enough can be displayed also in the reflective mold display using outdoor daylight.

[0106] Moreover, since said ECB mold liquid crystal display component 30 is what obtains coloring light using a birefringence operation of a liquid crystal layer and the polarization of polarizing plates 34 and 35, For example, even if it is going to change the color of each pixel to red, green, and blue and is going to display a full color image If the fluorescent material which emits the fluorescence of the color corresponding to the color from which high color purity cannot obtain all foreground colors easily with the ECB mold liquid crystal display component 30 although not necessarily obtained by high color purity is added in the electroluminescence layer 14 of above-mentioned EL element 10, the good color picture of color balance can be displayed.

[0107] In addition, although the liquid crystal display component 30 used for the liquid crystal display of the above-mentioned example is the thing of

an ECB mold, as for the case of the display using the light from the field emitter which is a back light 36 only for transparency molds, said liquid crystal display component 30 may display a color picture using a color filter.

[0108]

[Effect of the Invention] The inside of the incident light from the rear face where the field emitter of this invention counters the outgoing radiation side of an EL element in that outgoing radiation Since luminance distribution side, with the control-section material property which the light which the light which carried out incidence toward the predetermined direction went straight on, carried out [light] outgoing radiation to the front face, and carried out incidence toward other directions is scattered about, and carries out outgoing radiation to said front face is prepared The brightness of the light which carries out outgoing radiation in the predetermined direction can be made high, the outgoing radiation angle range where the outgoing radiation light of sufficient brightness is moreover obtained can be made large, and the luminance distribution of outgoing radiation light can be improved.

[0109] In the field emitter of this invention said luminance distribution control section material It consists of scatter reflection film inserted between the side faces of two or more area pellucida located in a line along the

direction of a field, and these area pellucida. If the thing on the field where said scatter reflection film met in said predetermined direction is desirable and luminance distribution considers such a control-section material as configuration The light which carried out incidence to said area pellucida toward the predetermined direction among the light which carries out incidence from the rear face can be made to be able to go straight on, and the light which carried out incidence toward other directions can be scattered about with said scatter reflection film.

[0110] Moreover, as for said luminance distribution control-section material, it is desirable to stick the rear face to the outgoing radiation side of an EL element, and to prepare it, the refractive index of said area pellucida is almost the same as the refractive index by the side of the outgoing radiation of said EL element, or it is still more desirable that it is a value near it. If it does in this way, since the light which carried out outgoing radiation will carry out incidence of the EL element a brightness distribution control member efficiently, outgoing radiation of the light which emitted light in the EL element can be carried out at high effectiveness, and the outgoing radiation light of high brightness can be obtained. [0111] Moreover, although an organic EL device is sufficient as said EL element, and depression of partial brightness arises in the luminance distribution of the outgoing radiation light from an EL element corresponding to the generating part of said dark spot when a dark spot peculiar to an organic EL device occurs in that case, the light which carries out outgoing radiation to the front face of said luminance distribution control-section material turns into light of luminance distribution which had depression of said brightness canceled by dispersion.

[0112] The liquid crystal display of this invention arranges said field emitter as that back light behind a liquid crystal display component. Moreover, this field emitter Since the outgoing radiation angle range where the outgoing radiation light of brightness with the brightness of the outgoing radiation light to a predetermined direction sufficient high moreover is obtained is wide, According to this liquid crystal display, the fall of the brightness of the screen when observing that display from across can be lessened, and the include angle range which can observe a display with sufficient brightness can be made large.

DESCRIPTION OF DRAWINGS

[Brief Description of the Drawings]

[Drawing 1] The sectional view which omitted hatching of the field illuminant by the 1st example of this invention.

[Drawing 2] The perspective view of the luminance distribution control-section

material used for said field emitter.

[Drawing 3] Drawing showing the luminance distribution of the outgoing radiation light of said field emitter in the luminance distribution of the conventional EL element, and the outgoing radiation side of the EL element as compared with luminance distribution when the diffusion plate has been arranged.

[Drawing 4] The sectional view which omitted hatching of the field illuminant by the 2nd example of this invention.

[Drawing 5] The perspective view showing the modification of luminance distribution control-section material.

[Drawing 6] The side elevation showing one example of the liquid crystal display of this invention.

[Drawing 7] The sectional view which omitted hatching of the conventional EL element.

[Description of Notations]

- 10 -- EL element
- 11 Transparence substrate
- 12 Outgoing radiation lateral electrode
- 13 ·· Background electrode
- 14 Electroluminescence layer
- 20 Luminance distribution control-section material
- 21 Area pellucida
- 22 Scatter reflection film
- 30 -- Liquid crystal display component
- 36 -- Back light (field emitter)

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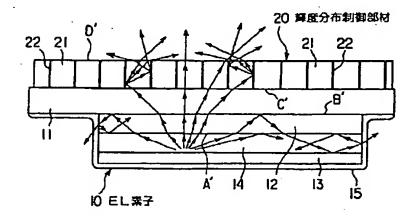
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(54) 【発明の名称】 面発光体およびそれを使用する液晶表示装置

(57)【要約】

【課題】E L素子を用いた面発光体として、所定の方向 に出射する光の輝度を高くし、しかも充分な輝度の出射 光が得られる出射角範囲を広くして出射光の輝度分布を 改善することができるものを提供する。

【解決手段】E L 素子10の出射面に、面方向に沿って並ぶ複数の透明部21とこれらの透明部の側面の間に挟まれた散乱反射膜22とからなる輝度分布制御部材20を設け、E L 素子10を出射して輝度分布制御部材20の透明部21に入射した光のうち、垂直な方向に向かって入射した光は直進させて出射し、斜め方向に向かって入射した光は散乱反射膜22で散乱させて出射するようにした。



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【特許請求の範囲】

【謂求項1】エレクトロルミネッセンス素子の出射面 に、その出射面に対向する裏面からの入射光のうち、所 定の方向に向かって入射した光が直進して表面に出射 し、他の方向に向かって入射した光が散乱して前記表面 に出射する特性をもった輝度分布制御部材を設けたこと を特徴とする面発光体。

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【請求項2】前記輝度分布制御部材は、その面方向に沿 って並ぶ複数の透明部とこれらの透明部の側面の間に挟 まれた散乱反射膜とからなっており、前記散乱反射膜 が、前記所定の方向に沿った面上にあることを特徴とす る請求項1に記載の面発光体。

【請求項3】前記輝度分布制御部材の裏面は前記エレク トロルミネッセンス素子の出射面に密着していることを 特徴とする請求項2に記載の面発光体。

【請求項4】前記輝度分布制御部材の透明部の屈折率 は、前記エレクトロルミネッセンス素子の出射側の屈折 率とほぼ同じかそれに近い値であることを特徴とする請 求項3に記載の面発光体。

エレクトロルミネッセンス素子であることを特徴とする 請求項1に記載の面発光体。

【請求項6】液晶表示素子と、その背後に配置された請 求項1に記載の面発光体とからなることを特徴とする液 ,,晶表示装置。

【発明の詳細な説明】

[0001]

【発明の属する技術分野】との発明は、エレクトロルミ ネッセンス素子(以下、EL素子という)を用いた面発 光体およびそれを使用する液晶表示装置に関するもので ある。

[0002]

【従来の技術】面発光体として用いられるEL素子は、 例えば液晶表示装置における液晶表示素子のバックライ トなどに使用されている。図7は従来のEL素子のハッ チングを省略した断面図であり、ここでは、有機EL素 子と呼ばれるものを示している。この有機EL素子は、 ガラスからなる透明基板 1 の一方の面に形成された透明 な出射側電極2と、この出射側電極2と対向する裏側電 極3との間に、有機材料からなる電界発光層4を介在さ せたものであり、前記出射側電極2はアノードとされ、 裏側電極3はカソードとされている。

【0003】なお、前記出射側電極2は、ITO(イン ジウム・スズ酸化物)またはインジウム・亜鉛酸化物か ちなっており、可視光波長域に対して高い透過性を有し ている。前記裏側電極3は、電界発光層4への電子注入 の観点から、仕事関数が小さいMg系合金(Mg-In 合金またはMg-Ag合金等)で形成されている。

【0004】また、図では前記電界発光層4を1つの層 として示したが、この電界発光層4は一般に、電子輸送 50 射した光は界面Bで全反射する。

性発光層のアノード側に正孔輸送層を積層した二層構 造、あるいは、発光層をはさんでアノード側に正孔輸送 層を積層しカソード側に電子輸送層を積層した三層構造 とされている。

【0005】この有機EL素子は、その出射側電極2と - 裏側電極3との間に電圧(直流電圧)を印加して発光駆 動されるものであり、この両電極2、3間に電圧を印加 すると、電界発光層4に、出射側電極(アノード)2か ら正孔が、裏側電極(カソード)3から電子が注入さ 10 れ、その注入された正孔と電子との再結合により一重項 励起子が発生して発光する。

【0006】そして、との一重項励起子による光は、電 界発光層4から出射側電極2に入射し、さらに透明基板 1を透過してその表面に出射する。なお、前記一重項励 起子が発する光には、電界発光層4の裏面側に向かう光 もあるが、その光は裏側電極3で反射される。

【0007】上記EL素子における電界発光層4の一点 からの光の出射経路をみると、この点からの光は図7に 矢線で示すように様々な方向に向かって放射するが、そ 【請求項5】前記エレクトロルミネッセンス素子は有機 20 のうち、出射面(基板1の表面)に垂直な方向(出射面 に対する垂線に沿った方向)に向かう光は、EL素子の 各層の界面および前記出射面と外気との界面を屈折や反 射を生じるととなく透過して垂直方向に出射する。

> 【0008】一方、斜め方向に向かう放射光は、前記各 層の界面に斜めに入射するため、その光は前記界面で屈 折または反射する。これは、電界発光層4の出射側の屈 折率、例えば三層構造の電界発光層における正孔輸送層 の屈折率が1.40~1.80、出射側電極2の屈折率 がITOの場合で約2.00、透明基板(ガラス)1の 屈折率が1.45~1.80であり、また外気である空 気の屈折率は1.0008程度であって、隣り合う層の 屈折率が互いに異なるためである。

> 【0009】このため、前記斜め方向に向かう放射光 は、まず電界発光層4と出射側電極2との界面Aに入射 し、その光のうち、前記界面Aに対して全反射臨界角よ り小さい入射角で入射した光がこの界面Aで屈折して出 射側電極2に入射し、全反射臨界角より大きい入射角で 入射した光は前記界面Aで全反射する。

【0010】なお、前記界面Aで全反射した光は、裏側 電極3での反射と前記界面Aおよび電界発光層4の横方 向の端面での反射とを繰り返して電界発光層4中をジグ ザグに屈折して進み、その過程で、前記界面Aに全反射 臨界角より小さい入射角で入射した光がこの界面Aを透 過して出射側電極2に入射する。

【0011】また、出射側電極2に入射した光は、この 出射側電極2を透過して透明基板1との界面Bに入射 し、その光のうち、前記界面Bに対して全反射臨界角よ り小さい入射角で入射した光がこの界面Bで屈折して透 明基板1に入射し、全反射臨界角より大きい入射角で入

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【0012】この界面Bで全反射した光のうちの一部の 光は、電界発光層4との界面Aでの全反射と前記界面B および出射側電極2の横方向の端面での反射とを繰り返 して出射側電極2中をジグザグに屈折して進み、その光 のうち、前記界面Bに全反射臨界角より小さい入射角で 入射した光がこの界面Bを透過して透明基板1に入射す る。

【0013】また、前記界面Bで全反射した他の光は、前記電界発光層4との界面Aを透過して電界発光層4に 戻るが、その光は、上記界面Aで全反射した光と同様に 10 電界発光層4中をジグザグに屈折して進み、その過程 で、前記界面Aに全反射臨界角より小さい入射角で入射 した光がこの界面Aを透過して出射側電極2に入射し、 そのうちの出射側電極2との界面Bに全反射臨界角より 小さい入射角で入射した光がこの界面Bを透過して透明 基板1に入射する。

【0014】さらに、出射側電極2から透明基板1に入射した光は、この透明基板1を透過してその表面と外気(空気)との界面Cに入射し、その光のうち、前記界面Cに対して全反射臨界角より小さい入射角で入射した光 20がこの界面Cで屈折して出射し、全反射臨界角より大きい入射角で入射した光は前記界面Cで全反射する。

【0015】この界面Cで全反射した光のうちの一部の 光は、出射側電極2との界面Bでの全反射と前記界面A ♪および透明基板1の横方向の端面での反射とを繰り返し て透明基板1中をジグザグに屈折して進み、その光のう ち、前記界面Cに全反射臨界角より小さい入射角で入射 した光がこの界面Cを透過して出射する。

【0016】また、前記界面Cで全反射した他の光は、前記出射側電極2との界面Bを透過して出射側電極2に戻るか、さらに電界発光層4との界面Aを透過して電界発光層4に戻るが、その光は、上記のように出射側電極2中または電界発光層4中をジグザグに屈折して進み、そのうちの前記界面A。Bに全反射臨界角より小さい入射角で入射した光が再び透明基板1に入射して、その光のうち、前記外気との界面Cに対して全反射臨界角より小さい入射角で入射した光が出射する。

【0017】すなわち、上記EL素子では、電界発光層 4と出射側電極2との界面Aおよび出射側電極2と透明 基板1との界面Bに対して全反射臨界角より小さい入射 角で入射してこれらの界面A、Bを透過し、さらに出射面である前記透明基板1の表面と外気との界面Cに対して全反射臨界角より小さい入射角で入射した光が出射光となる。

【0018】なお、他の光は各界面A、B、Cのいずれかで全反射するが、これらの光は、上述したように、電界発光層4、出射側電極2、および透明基板1を屈折しながら進むが、その過程で、一部の光が前記出射側電極2や電界発光層4および透明基板1の端面から出射して漏れ光となる。

【0019】したがって、最終的に出射面に出射する光は、出射面と外気との界面Cに対して全反射臨界角より小さい入射角で入射する光であり、図7に示すように、電界発光層4で発光した光の出射側電極2との界面Aでの垂直方向(出射面に対する垂線に沿った方向)に対する角度を入射角α、出射側電極2と透明基板1との界面での前記垂直方向に対する角度を入射角α、出射面からの前記垂直方向に対する角度を出射角るとすると、最終的に出射面から出射する光、つまり出射角δが90°より小さい範囲の光は、電界発光層4で発光した光のうちの、前記界面A、B、Cに対して次のような入射角α、β、γで入射する光である。

[0021]

【発明が解決しようとする課題】しかし、上記従来のEL素子は、その正面方向つまり出射面に垂直な方向に出射する光(出射角 $\delta=0$ の光)の輝度は高いが、出射角 δ が大きくなるのにともなってその輝度が急激に低下するため、出射光の輝度分布が指向性の強い分布であり、したがって、高輝度の出射光が得られる出射角範囲が狭いという問題をもっている。

【0022】そして、EL素子は、例えば液晶表示装置における液晶表示素子のバックライトなどに利用されているが、上記従来のEL素子は、その出射光の輝度分布が指向性の強い分布であるため、このEL素子を前記バックライトとする液晶表示装置は、その表示を出射面に垂直な方向に対して斜め方向から観察すると画面がかなり暗くなってしまうから、表示を充分な明るさで観察できる角度範囲が狭いという問題をもっている。

[0023] そこで、従来から、EL素子の出射光を拡 散板で拡散して出射光の輝度分布をほぼ均一にすること が考えられているが、これでは、EL素子からの高輝度 の出射角範囲の出射光も拡散してその輝度が低下するた め、所定の方向(例えば正面方向)に出射する光の輝度 を高くすることができない。

【0024】との発明は、EL素子を用いた面発光体として、所定の方向に出射する光の輝度を高くし、しかも充分な輝度の出射光が得られる出射角範囲を広くして出射光の輝度分布を改善することができるものを提供するとともに、あわせて、その面発光体を用いた液晶表示装50 置を提供することを目的としたものである。

[0025]

【課題を解決するための手段】との発明の面発光体は、 EL素子の出射面に、その出射面に対向する裏面からの 入射光のうち、所定の方向に向かって入射した光が直進」 して表面に出射し、他の方向に向かって入射した光が散 乱して前記表面に出射する特性をもった輝度分布制御部 材を設けたことを特徴とするものである。

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【0026】すなわち、との発明の面発光体は、EL素 子において発光してその表面に出射する光を、前記輝度 分布制御部材を介して出射するようにしたものであり、 との面発光体によれば、前記EL素子を出射して輝度分 布制御部材にその裏面から入射した光のうち、所定の方 向に向かって入射した光は直進して表面に出射し、他の 方向に向かって入射した光は散乱して前記表面に出射す るため、前記所定の方向への出射光の輝度を高くし、し かも充分な輝度の出射光が得られる出射角範囲を広くし て出射光の輝度分布を改善することができる。

【0027】また、この発明の液晶表示装置は、液晶表 示素子の背後に、そのバックライトとして前記面発光体 を配置したものであり、この面発光体は、所定の方向へ の出射光の輝度が高く、しかも充分な輝度の出射光が得 られる出射角範囲が広いため、この液晶表示装置によれ ば、その表示を斜め方向から観察したときの画面の明る さの低下を少なくして、表示を充分な明るさで観察でき *る角度範囲を広くすることができる。

[0028]

【発明の実施の形態】との発明の面発光体は、上記のよ うに、EL素子の出射面に、その出射面に対向する裏面 からの入射光のうち、所定の方向に向かって入射した光 が直進して表面に出射し、他の方向に向かって入射した 30 光が散乱して前記表面に出射する特性をもった輝度分布 制御部材を設けることにより、所定の方向への出射光の 輝度を高くし、しかも充分な輝度の出射光が得られる出 射角範囲を広くして出射光の輝度分布を改善したもので

【0029】との発明の面発光体において、前記輝度分 布制御部材は、その面方向に沿って並ぶ複数の透明部と これらの透明部の側面の間に挟まれた散乱反射膜とから なっており、前記散乱反射膜が、前記所定の方向に沿っ た面上にあるものが望ましく、輝度分布制御部材をこの ような構成とすれば、その裏面から前記透明部に入射す る光のうち、所定の方向に向かって入射した光を直進さ せ、他の方向に向かって入射した光を前記散乱反射膜に より散乱することができる。

【0030】また、前記輝度分布制御部材は、その裏面 を E L 素子の出射面に密着させて設けるのが望ましく、 さらに前記透明部の屈折率は、前記EL素子の出射側の 屈折率とほぼ同じかそれに近い値であるのが好ましい。 【0031】とのように、前記輝度分布制御部材の裏面 がEL素子の出射面に密着しているとともに、前記透明 部の屈折率がEL素子の出射側の屈折率とほぼ同じかそ れに近い値であれば、EL素子を出射した光が効率良く 輝度分布制御部材に入射するため、EL素子において発 光した光を高い効率で出射させてより高輝度の出射光を 得るととができる。

【0032】また、前記EL素子は有機EL素子でよ く、その場合は、有機EL素子特有のダークスポットが 発生したときに、EL素子からの出射光の輝度分布に前 記ダークスポットの発生箇所に対応して部分的な輝度の 10 落ち込みが生じるが、前記輝度分布制御部材の表面に出 射する光は、散乱により前記輝度の落ち込みを解消され た輝度分布の光になるから、EL素子にダークスポット が発生しても、部分的な輝度の落ち込みのない良好な輝 度分布の光を出射することができる。

【0033】とれは、特に前記面発光体をバックライト とする液晶表示装置において効果的であり、この液晶表 示装置によれば、前記面発光体のEL素子にダークスポ ットが発生しても、液晶表示素子には輝度の落ち込みを 解消された輝度分布の光が入射するため、前記ダークス ポットの発生箇所に対応する画素の輝度低下がない高品 質の画像を表示することができる。

[0034]

【実施例】図1はこの発明の第1の実施例による面発光 体のハッチングを省略した断面図である。との面発光体 は、EL素子10の出射面に、その出射面に対向する裏 面からの入射光のうち、所定の方向に向かって入射した 光が直進して表面に出射し、他の方向に向かって入射し た光が散乱して前記表面に出射する特性をもった輝度分 布制御部材20を設けたものである。

【0035】まず、EL索子10について説明すると、 このEL素子本体10は、ガラスからなる透明基板11 の一方の面に形成された透明な出射側電極12と、との 出射側電極12と対向する裏側電極13との間に、有機 材料からなる電界発光層14を介在させた有機EL素子 であり、その出射側電極12はアノードとされ、裏側電 極13はカソードとされている。

【0036】なお、前記出射側電極12は、ITOまた はインジウム・亜鉛酸化物からなっており、前記裏側電 極13は、仕事関数が小さい、Mg-ln合金またはM g-Ag合金等のMg系合金で形成されている。

【0037】ただし、前記Mg系合金は反応性が高いた め、このMg系合金からなる裏側電極13が空気中の水 分と反応して劣化したり、酸素と反応して酸化したりす。 るおそれがある。

【0038】そのため、この実施例では、図1に示した ように、前記EL素子10の周囲をその裏面全体から透 明基板11の下面にわたって気密性の高い樹脂膜15で 被覆し、前記Mg系合金からなる裏側電極13を空気か **ら完全に遮蔽している。**

【0039】また、図1では前記電界発光層14を1つ

の層として示したが、との電界発光層 1 4 は、電子輸送 性発光層のアノード側に正孔輸送層を積層した二層構造 か、あるいは、発光層をはさんでアノード側に正孔輸送 層を積層しカソード側に電子輸送層を積層した三層構造 となっている。

【0040】なお、例えば電界発光層 14 を三層構造とする場合、発光層は、DPVBi $\{4, 4'- \forall Z (2, 2- \forall Z) \}$ とBCz VBi $\{4, 4'- \forall Z (2- \lambda Z) \}$ とBCz VBi $\{4, 4'- \forall Z (2- \lambda Z) \}$ とを、DPVBi を 2 を

【0041】前記電界発光層14の出射側の層の屈折率、つまりα-NPDからなる正孔輸送層の屈折率は1.40~1.80であり、また、出射側電極12の屈折率は1TOの場合で約2.00、透明基板(ガラス)1の屈折率は1.45~1.80である。

【0042】このEL素子10は、その田射側電極12と裏側電極13との間に電圧(直流電圧)を印加して発光駆動されるものであり、この両電極12、13間に電圧を印加すると、電界発光層14に、出射側電極(アノード)12から正孔が、裏側電極(カソード)13から電子が注入され、その注入された正孔と電子との再結合により一重項励起子が発生して発光する。

【0043】そして、との一重項励起子による光は、電界発光層14から出射側電極12に入射し、さらに透明 30基板11を透過してその表面に出射する。なお、前記一重項励起子が発する光には、電界発光層14の裏面側に向かう光もあるが、その光は裏側電極13で反射される。

【0044】なお、前記電界発光層14が、上記DPVBiとBCzVBiからなる発光層と、α-NPDからなる正孔輸送層と、Alq3からなる電子輸送層とを積層した三層構造である場合、この電界発光層14において発光する光は、可視光帯域の全ての波長を含むが、そのうちの青の波長域の光量が若干多い波長成分の光であり、したがって、発光色が青味を帯びた色になる。

【0045】そこで、この実施例では、前記電界発光層 14の発光層または出射側の正孔輸送層中に、赤の蛍光 物質と緑の蛍光物質を適量ずつ分散させ、発光した光の 一部を前記蛍光物質に吸収させて赤と緑の蛍光を発生さ せることにより、前記EL素子10を出射する光の色を 白色に近づけるようにしている。

【0046】次に、上記輝度分布制御部材20について 説明する。図2は前記輝度分布制御部材20の斜視図で ある。この輝度分布制御部材20は、その面方向に沿っ て並ぶ複数の透明部21と、これらの透明部21の側面の間に挟まれた、両面がいずれもである散乱反射膜22とからなるフィルムからなっており、前記散乱反射膜22は、所定の方向に沿った面上にある。以下、この輝度分布制御部材20を輝度分布制御フィルムという。

【0047】なお、前記散乱反射膜22としては、アルミニウムまたは銀等の無機金属、ポリアセチレン誘導体を含む有機金属などの反射性微結晶膜や、酸化チタン、酸化亜鉛、酸化アルミニウム、酸化マグネシウム等の金属酸化物の焼結体からなる拡散性膜を用いる。

【0048】この輝度分布制御フィルム20は、前記散乱反射膜22が、フィルム面に垂直な方向に沿った面上にあるものであり、この輝度分布制御フィルム20は、その縦横のいずれかの幅方向に沿った直線状の散乱反射膜22が前記透明部21の幅に相当する間隔で互いに平行に並んでいるルーバー状をなしている。

【0049】なお、このルーバー状の輝度分布制御フィルム20は、例えば、前記透明部21の幅に相当する厚さの透明な樹脂層と前記散乱反射膜22とを交互に積層し、その積層グロックを厚さ方向(積層方向)に垂直な切断面に沿ってフィルム状にスライスする方法で製造できる。

【0050】また、前記輝度分布制御フィルム20の透明部21は、屈折率が上記EL素子10の出射側の屈折率(この実施例では透明基板11の屈折率)とほぼ同じかそれに近い値である透明樹脂からなっている。

【0051】なお、EL素子10の出射側の屈折率、つまりガラスからなる透明基板11の屈折率は1.45~1.80であるが、それとほぼ同じかまたは近い値の屈折率をもつ透明樹脂としては、PET(ポリエチレンテレフタレート)、PES(ポリエーテルサルフォン)、PC(ポリカーボネート)等があり、これらの樹脂の屈折率は1.40~1.60である。

【0052】そして、前記輝度分布制御フィルム20は、上記EL素子10の出射面に、フィルム裏面をEL素子10の出射面(透明基板11の表面)に密着させて設けられている。なお、この実施例では、輝度分布制御フィルム20を、その透明部21の屈折率とEL素子10の透明基板11の屈折率のうちの一方とほぼ同じか、あるいは両方の屈折率の間の屈折率をもった透明接着剤(図示せず)によりEL素子10に接着している。

【0053】上記面発光体は、EL素子10の電界発光層14において発光してEL素子10の表面に出射する光を、前記輝度分布制御フィルム20を介して出射するようにしたものである。

【0054】まず、EL素子10の電界発光層14において発光した光のEL素子表面への出射経路を、前記電界発光層14の一点からの光についてみると、この点からの光は図1に矢線で示すように様々な方向に向かって50 放射するが、そのうち、EL素子10の出射面に垂直な

方向(出射面に対する垂線に沿った方向)に向かう光 は、電界発光層14と出射側電極12との界面A′およ び前記出射側電極12と透明基板11との界面B^、を屈 折や反射を生じることなく透過してEL素子表面に垂直 に出射する。

【0055】一方、斜め方向に向かう放射光は、前記各 界面A′、B′に斜めに入射するが、前記電界発光層1 4と出射側電極12および透明基板11の屈折率は上述 したような値であって隣り合う層の屈折率が互いに異な るため、前記斜め方向に向かう放射光は、前記各界面 A′、B′で屈折または反射する。

【0056】すなわち、斜め方向に向かう放射光は、ま ず電界発光層14と出射側電極12との界面A′に入射 し、その光のうち、前記界面A′に対して全反射臨界角 より小さい入射角で入射した光がこの界面A'で屈折し て出射側電極12内に入射し、全反射臨界角より大きい 入射角で入射した光は前記界面A´で全反射する。

【0057】なお、前記界面A、で全反射した光は、裏 側電極13で反射されるとともに前記界面A′および電 ザグに屈折して進み、その過程で、前記界面A'に全反 射臨界角より小さい入射角で入射した光がこの界面A' を透過して出射側電極2内に入射する。

【0058】また、出射側電極12に入射した光は、と ★の出射側電極12内を透過して透明基板11との界面 B'に入射し、その光のうち、前記界面B'に対して全 反射臨界角より小さい入射角で入射した光がこの界面 B'で屈折して透明基板11内に入射し、全反射臨界角 より大きい入射角で入射した光は界面B´で全反射す る。

【0059】この界面B'で全反射した光のうちの一部 の光は、電界発光層 14との界面 A′での全反射と前記 界面 B′ および出射側電極 12の横方向の端面での反射 を繰り返して出射側電極12中をジグザグに屈折して進 み、その光のうち、前記界面B′に全反射臨界角より小 さい入射角で入射した光がこの界面B、を透過して透明 基板11に入射する。

【0060】また、前記界面B′で全反射した他の光 は、前記電界発光層14との界面A'を透過して電界発 光層14に戻るが、その光は、上記界面A′で全反射し た光と同様に電界発光層14中をジグザグに屈折して進 み、その過程で、前記界面A′に全反射臨界角より小さ い入射角で入射した光がとの界面A、を透過して出射側 電極2に入射し、そのうちの出射側電極2との界面B' に全反射臨界角より小さい入射角で入射した光がこの界 面B′を透過して透明基板11に入射する。

【0061】そして、出射側電極12から透明基板11 に入射した光は、この透明基板 1 1 を透過してその表面 に出射し、上記輝度分布制御フィルム20の透明部21 にその裏面から入射する。

【0062】この場合、この実施例では、前記輝度分布 制御フィルム20の透明部21の屈折率を、EL素子1 0の出射側の屈折率(透明基板11の屈折率)とほぼ同 じかそれに近い値にするとともに、この輝度分布制御フ ィルム20を、その透明部21の屈折率とEL素子10. の透明基板 1 1 の屈折率のうちの一方とほぼ同じか、あ るいは両方の屈折率の間の屈折率をもった図示しない透 明接着剤によりEL素子10に接着しているため、EL 累子10の表面と輝度分布制御フィルム20との界面 10 C'に入射した光は、その入射角がどのような角度であ っても、そのほとんどが全反射することなく前記界面 C′を透過して輝度分布制御フィルム20の透明部21 に入射する。

【0063】次に、前記輝度分布制御フィルム20の透 明部21に入射した光の出射経路を説明すると、との透 明部21にその裏面から入射した光のうち、散乱反射膜 22に沿った方向、つまり輝度分布制御フィルム20の フィルム面に垂直な方向に向かって入射した光(EL素 子10から垂直に出射した光)は、前記透明部21を直 界発光層 14の端面で反射して電界発光層 14中をジグ 20 進して輝度分布制御フィルム20の表面に垂直に出射す る。

> 【0064】一方、前記透明部21に他の方向に向かっ て入射した光、つまり輝度分布制御フィルム20のフィ ルム面に対して斜めに入射した光は、透明部21を斜め に透過してその側面の散乱反射膜22に入射し、その散 乱反射面で散乱する。

【0065】なお、前記透明部21を斜めに透過する光 のなかには、前記散乱反射膜22に入射せずにそのまま 透明部21の表面に達する光もあり、その光は、散乱す 30 ることなく輝度分布制御フィルム20の表面に出射す る。との出射光は、透明部21の表面と外気との界面 D′において、この界面D′に対する入射角と、前記透 明部21と外気(空気)との屈折率差に応じて屈折し、 その方向に出射する。

【0066】前記散乱反射膜22で散乱した光は、透明 部21中を様々な方向に向かって進み、そのうちの透明 部21の表面に向かう光が、前記外気との界面D′に入 射する。

【0067】なお、他の方向に向かう光は、直接は前記 界面D′に入射しないが、その光のほとんどが反対側の 散乱反射膜22に入射して再び散乱し、その散乱光のう ちの透明部21の表面に向かう光が前記界面D′ に入射 するため、前記透明部21に入射した光はそのほとんど が前記界面 D′ に入射する。

【0068】そして、前記透明部21の表面と外気との 界面D'に入射した光のうち、前記界面D'に対して全 反射臨界角より小さい入射角で入射した光は、との界面 D′を透過して輝度分布制御フィルム20の表面に出射 する。この出射光は、前記界面D′において、この界面 50 D'に対する入射角と、前記透明部21と外気(空気)

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との屈折率差に応じて屈折し、その方向に出射する。 【0069】また、前記界面D′に全反射臨界角より大 きい入射角で入射した光は、この界面D'で全反射する が、その光はその反射方向の散乱反射膜22に入射して... 再び散乱するため、これらの光も最終的には前記界面 D' に全反射臨界角より小さい入射角で入射し、この界 面D′を透過して輝度分布制御フィルム20の表面に出 射する。

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【0070】このように、上記面発光体によれば、EL 素子10を出射して輝度分布制御フィルム20にその裏 10 面から入射した光のうち、垂直な方向に向かって入射し た光は直進して表面に出射し、他の方向に向かって入射 した光は散乱して前記表面に出射するため、前記垂直な 方向への出射光の輝度を高くし、しかも充分な輝度の出 射光が得られる出射角範囲を広くして出射光の輝度分布 を改善することができる。

【0071】なお、輝度分布制御フィルム20において 散乱した光のなかには、前記輝度分布制御フィルム20 の表面と外気との界面D′に垂直に入射する光もあり、 その光は前記界面D、で屈折することなく垂直に出射す るため、前記垂直な方向への出射光の輝度は、輝度分布 制御フィルム20を垂直に透過して表面に出射する直進 光の輝度よりもさらに高くなる。

【0072】しかも、上記面発光体によれば、EL素子 10を出射して輝度分布制御フィルム20の各透明部2 1 に入射した光のうち、最終的な出射面である前記透明 部21の表面と外気との界面D′に向かって全反射臨界 角より大きい入射角で進む光が散乱して方向を変え、そ の光が前記界面D′に全反射臨界角より小さい入射角で 入射してこの界面D'を透過して出射するため、EL素 30 たがって、高輝度の出射光が得られる出射角範囲が狭 子10から輝度分布制御フィルム20に入射した光の出 射効率を高くすることができる。

【0073】さらに、従来のEL素子では、図7に示し たように、各界面A, B, Cで全反射した光が電界発光 層4、出射側電極2、および透明基板1を屈折しながら 進む過程で、その一部の光が前記出射側電極2や電界発 光層4および透明基板1の端面から出射して漏れ光とな るため、EL素子を出射するまでの過程での光のロスが 大きく、したがって電界発光層4での発光エネルギーに 比べて出射光量がかなり少なくなるが、上記面発光体に 40 よれば、EL素子10を出射するまでの過程での光のロ スも少ない。

【0074】すなわち、上記面発光体においても、図1 に示したように、界面A'およびB'で全反射した光が 電界発光層 14 および出射側電極 12を屈折しながら進 む過程で、その一部の光が前記出射側電極2や電界発光 層4および透明基板1の端面から出射して漏れ光となる が、透明基板11に入射した光は、上述したように、透 明基板11と輝度分布制御フィルム20との界面C^に 対する入射角がどのような角度であっても、そのほとん 50 を効率良く出射することができる。

どが全反射することなく前記界面C′を透過して輝度分 布制御フィルム20の透明部21に入射するため、従来 のEL素子のような透明基板の端面からの漏れ光はほと んど生じない。

【0075】したがって、上記面発光素子によれば、E L素子10を出射し、さらに輝度分布制御フィルム20 を透過して出射する光量を、従来のEL素子の出射光量 に比べて飛躍的に多くして(少なくとも2倍以上)、高 輝度の出射光を得ることができる。

【0076】図3は上記面発光体の出射光の輝度分布 を、従来のEL素子の輝度分布およびそのEL素子の出 射面に拡散板を配置したときの輝度分布と比較して示す 図であり、実線は上記実施例の面発光体の輝度分布、破 線は従来のEL素子の輝度分布、一点鎖線は従来のEL 素子の出射面に拡散板を配置したときの輝度分布を示し ている。

【0077】なお、図3に示した上記面発光体の輝度分 布は、面発光体の出射面(輝度分布制御フィルム20の 表面)に垂直でかつ輝度分布制御フィルム20の透明部 21および散乱反射膜22の長さ方向に対して直交する 方向に沿った面上における輝度分布であり、図におい $T_{\chi} + \theta$ は出射面に垂直な方向(出射角 $\theta = 0$ の方 向)に対して一方の方向に出射する光の出射角、 $-\theta$ は 前記垂直な方向に対して反対方向に出射する光の出射角 である。

【0078】この図3のように、従来のEL素子の輝度 分布は、正面方向(出射面に垂直な方向)に出射する光 の輝度は高いが、出射角が大きくなるのにともなってそ の輝度が急激に低下する、指向性の強い分布であり、し

【0079】また、従来のEL素子の出射面に拡散板を 配置したときの輝度分布は、ほぼ均一な分布であるが、 EL素子からの高輝度の出射角範囲の出射光も拡散する ため、正面方向に出射する光の輝度が、従来のEL素子 に比べてかなり低い。

【0080】とれらに比べて、上記実施例の面発光体の 輝度分布は、正面方向への出射光の輝度が高く、しかも 充分な輝度の出射光が得られる出射角範囲が広い分布で あり、しかも、輝度分布制御フィルム20を垂直に透過 して表面に出射する直進光のほかに、前記輝度分布制御 フィルム20において散乱した光のうちの外気との界面 D'に垂直に入射した光も垂直に出射するため、正面方 向に出射する光の輝度が従来のEL素子よりもさらに高

【0081】また、上記実施例の面発光体は、そのEL 素子10として、導電性髙分子からなる電界発光層14 を備えた有機EL素子を用いており、有機EL索子はそ の電界発光層14の光の透過率が高いため、発光した光

【0082】また、前記有機EL素子は、その電界発光 層14が有機材料からなっているため、この電界発光層 14と金属材料からなる出射側電極12との界面にダー クスポットと呼ばれる発光不良部分が発生することがあ り、このダークスポットが発生すると、EL素子10か らの出射光の輝度分布に前記ダークスポットの発生箇所 に対応して部分的な輝度の落ち込みが生じるが、前記輝 度分布制御フィルム20の表面に出射する光は、散乱に より前記輝度の落ち込みを解消された輝度分布の光であ るため、上記面発光体によれば、EL索子10に有機E 10 し素子特有のダークスポットが発生しても、輝度の落ち 込みを解消された輝度分布の光になるから、EL素子1 0にダークスポットが発生しても、部分的な輝度の落ち 込みのない良好な輝度分布の光を出射することができ る。

【0083】図4はこの発明の第2の実施例による面発 光体のハッチングを省略した断面図である。この実施例 の面発光体は、EL素子10の透明基板を輝度分布制御 フィルム20で兼用したものであり、EL素子10の基 記第1の実施例と同じである。

【0084】ただし、この実施例では、前記輝度分布制 御フィルム20の透明部21を、屈折率が、EL素子1 0の出射側の屈折率(電界発光層14を三層構造とする 場合は、その出射側の層である正孔輸送層の屈折率)と ほぼ同じかそれに近い値である透明樹脂で形成してい る。・

> 【0085】この実施例の面発光体によれば、EL素子 10を出射する光、つまりEL素子10と輝度分布制御 フィルム20との界面に入射した光が、その入射角がど 30 のような角度であっても、全反射することなく前記界面 を透過して輝度分布制御フィルム20の透明部21に入 射するため、EL素子10の電界発光層14で発光した 光がEL素子10を出射する過程での全反射は、その出 射経路を図4に矢線で示したように、電界発光層14と 出射側電極12との界面で発生するだけであり、したが って全反射した光の漏れは、ほぼ電界発光層14の端面 からの漏れだけになるため、上記第1の実施例よりもさ らに出射光量を多くすることができる。

【0086】なお、上記第1および第2の実施例では、 輝度分布制御フィルム20として、散乱反射膜22がフ ィルム面に垂直な方向に沿った面上にあるものを用いた が、前記散乱反射膜22の散乱反射面は傾斜面であって もよい。

【0087】とのような輝度分布制御フィルムを用いれ ば、EL素子を出射して輝度分布制御フィルムにその裏 面から入射した光のうち、散乱反射膜22に沿った方向 に向かって入射した光が直進して表面に出射し、他の方 向に向かって入射した光は散乱して前記表面に出射する

な輝度の出射光が得られる出射角範囲を広くして出射光 の輝度分布を改善することができる。

【0088】また、上記実施例では電界発光層14とし て、青色の光を発する発光層に赤の蛍光を発する蛍光物 質と緑の蛍光を発する蛍光物質とを分散状態に含有させ たものを用いたが、これに限らず、例えば赤色の光を発 するドット状の発光層と、緑色の光を発するドット状の 発光層と、青色の光を発するドット状の発光層とを交互 に並べて形成して、EL素子10を出射する光の色を白 色にするようにしてもよい。

【0089】さらに、上記実施例では、EL素子10の 出射面に設ける輝度分布制御部材として、直線状の散乱 反射膜22が透明部21の幅に相当する間隔で互いに平 行に並んでいるルーバー状の輝度分布制御フィルム20 を用いたが、前記輝度分布制御部材は、透明なフィルム 中に散乱反射膜を格子状に設けたものでも、透明フィル ム中に長さの短い散乱反射膜を縦幅方向および横幅方向 に適当なピッチで設けたものでもよい。

【0090】図5は輝度分布制御部材の変形例を示す斜 本的な構造と、輝度分布制御フィルム20の構造は、上 20 視図であり、この輝度分布制御部材は、上記実施例で用 いたルーバー状の輝度分布制御フィルム20を2枚、そ れぞれの散乱反射膜22の長さ方向を互いに直交させて 重ね合わせたものである。

> [0091] このような輝度分布制御部材を用いれば、 散乱反射膜22が格子状に設けられているため、入射光 が互いに直交する2つの方向に散乱するから、前記2つ の方向の出射光の輝度分布をそれぞれ図3のような分布 にすることができる。

> 【0092】なお、上記輝度分布制御部材は、透明なフ ィルム中に散乱反射膜を設けたものに限らず、裏面から の入射光のうち、所定の方向に向かって入射した光が直 進して表面に出射し、他の方向に向かって入射した光が 散乱して前記表面に出射する特性をもったものであれば よい。

> 【0093】次に、上記面発光体を用いた液晶表示装置 について説明する。図6は前記液晶表示装置の一実施例 を示す側面図であり、この液晶表示装置は、液晶表示素 子30の背後に、そのバックライト36として、上述し た面発光体を配置したものである。

【0094】上記液晶表示素子30は、単純マトリック スまたはアクティブマトリックス方式のECB(複屈折 効果)型液晶表示素子であり、枠状シール材33を介し て接合した一対の透明な電極形成基板31、32間に、 液晶分子が所定の配向状態(例えばツイスト配向状態) に配向した液晶層を設けるとともに、前記基板31,3 2の外面にそれぞれ偏光板34,35を配置したもので ある。

【0095】とのECB型液晶表示素子30は、液晶層 の複屈折作用と偏光板34、35の偏光作用とを利用し ため、斜め方向への出射光の輝度を高くし、しかも充分 50 て着色光を得るものであり、一方の偏光板を透過して入 射した直線偏光が、液晶層を透過する過程で液晶の複屈 折作用により各波長光がそれぞれ偏光状態の異なる楕円 **偏光となった光となり、その光が他方の偏光板に入射し** て、この他方の偏光板を透過した光が、その光を構成す る各波長光の光強度の比に応じた色の着色光になる。

【0096】すなわち、このECB型液晶表示素子30 は、カラーフィルタを用いずに着色光を得るものであ り、したがってカラーフィルタによる光の吸収がないか ら、光の透過率を高くして、明るいカラー表示を得ると とができる。

【0097】そして、ECB型液晶表示素子30は、そ の両基板31、32の電極間に印加される電圧に応じた 液晶分子の配向状態によって液晶の複屈折性が変化し、 それに応じて他方の偏光板に入射する各波長光の偏光状 態が変化するため、印加電圧を制御することによって着 色光の色を変化させ、同じ画素で複数の色を表示して、 フルカラー画像等の多色カラー画像を表示することがで きる。

【0098】また、との実施例では、前記パックライト 36として、図1に示した第1の実施例の面発光体を用 いている。この面発光体の構成の説明は、図に同符号を 付して省略する。

【0099】この液晶表示装置は、その液晶表示素子3 0のバックライト36として、上述したような、所定の ♪方向への出射光の輝度が高く、しかも充分な輝度の出射 光が得られる出射角範囲が広い面発光体を用いているた め、その表示を斜め方向から観察したときの画面の明る さの低下を少なくして、表示を充分な明るさで観察でき る角度範囲を広くすることができる。

【0100】しかも、上記面発光体は、EL素子10を 出射し、さらに輝度分布制御フィルム20を透過して出 射する光量が、従来のEL素子の出射光量に比べて飛躍 的に多いものであるため、高輝度の光を液晶表示素子3 0 に入射させ、高輝度の画像を表示させることができ

【0101】また、上記液晶表示装置は、バックライト 36に上記面発光体を用いたものであり、この面発光体 の発光源であるEL素子10の裏側電極13で光を反射 することができるため、前記EL素子10を発光駆動せ ずに、液晶表示素子30の出射面側から入射する外光

(自然光または室内照明光)を図6に破線で示すように 前記EL素子10の裏側電極13で反射させて表示する ことも可能であり、したがって、バックライト36から の光を利用する透過型表示と、外光を利用する反射型表 示との両方を行なえる、いわゆる2ウエイ表示装置とし て使用することができる。

【0102】この場合、上記実施例の面発光体は、EL 素子10に、その電界発光層14の光の透過率が高い有 機EL素子を用いたものであるため、発光した光を効率 良く出射することができるだけでなく、反射型表示を行 50 なっており、前記散乱反射膜が、前記所定の方向に沿っ

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なう場合も、入射した外光を裏側電極13で効率良く反 射して明るい表示を得ることができる。

【0103】また、前記面発光体の輝度分布制御フィル ム20を、その各散乱反射膜22を液晶表示素子30の 各画素の行間および列間にそれぞれ対応させて格子状に 設けたものとし、前記液晶表示素子30に前記格子状の 散乱反射膜22に対応したブラックマスクを設ければ、 散乱反射膜22自体の光反射による表示のちらつきを防 止できるとともに、EL素子10からの出射光を効率良 10 く液晶表示素子30の各画素に入射することができる。 【0104】なお、前記EL素子10は、有機EL素子 特有のダークスポットを発生することがあるが、その場 合でも、面発光体からの出射光(輝度分布制御部材の表 面に出射する光)は、散乱により前記輝度の落ち込みを 解消された輝度分布の光になるから、部分的な輝度の落 ち込みのない良好な輝度分布の光を液晶表示素子30に 入射させて、高品質の画像を表示することができる。

【0105】しかも、この液晶表示装置では、液晶表示 素子30として、カラーフィルタを用いずに着色光を得 るECB型液晶表示素子を用いているため、外光を利用 する反射型表示においても、充分に明るいカラー画像を 表示することができる。

【0106】また、前記ECB型液晶表示素子30は、 液晶層の複屈折作用と偏光板34.35の偏光作用とを 利用して着色光を得るものであるため、例えば各画素の 色を赤、緑、青に変化させてフルカラー画像を表示しよ うとしても、全ての表示色を高い色純度で得られるとは 限らないが、ECB型液晶表示素子30では高い色純度 が得にくい色に対応した色の蛍光を発する蛍光物質を上 30 記EL素子10の電界発光層14に添加しておけば、色 バランスの良いカラー画像を表示することができる。

【0107】なお、上記実施例の液晶表示装置に用いた 液晶表示素子30はECB型のものであるが、バックラ イト36である面発光体からの光を利用する透過型専用 の表示装置の場合は、前記液晶表示素子30はカラーフ ィルタを用いてカラー画像を表示するものであってもよ いる

[0108]

【発明の効果】との発明の面発光体は、EL素子の出射 40 面に、その出射面に対向する裏面からの入射光のうち、 所定の方向に向かって入射した光が直進して表面に出射 し、他の方向に向かって入射した光が散乱して前記表面 に出射する特性をもった輝度分布制御部材を設けたもの であるから、所定の方向に出射する光の輝度を高くし、 しかも充分な輝度の出射光が得られる出射角範囲を広く して出射光の輝度分布を改善することができる。

【0109】との発明の面発光体において、前記輝度分 布制御部材は、その面方向に沿って並ぶ複数の透明部と これらの透明部の側面の間に挟まれた散乱反射膜とから

た面上にあるものが望ましく、輝度分布制御部材をとのような構成とすれば、その裏面から前記透明部に入射する光のうち、所定の方向に向かって入射した光を直進させ、他の方向に向かって入射した光を前記散乱反射膜により散乱することができる。

【0110】また、前記輝度分布制御部材は、その裏面をEL素子の出射面に密着させて設けるのが望ましく、さらに前記透明部の屈折率は、前記EL素子の出射側の屈折率とほぼ同じかそれに近い値であるのが好ましい。このようにすれば、EL素子を出射した光が効率良く輝 10度分布制御部材に入射するため、EL素子において発光した光を高い効率で出射させてより高輝度の出射光を得ることができる。

【0111】また、前記EL素子は有機EL素子でよく、その場合は、有機EL素子特有のダークスポットが発生したときに、EL素子からの出射光の輝度分布に前記ダークスポットの発生箇所に対応して部分的な輝度の落ち込みが生じるが、前記輝度分布制御部材の表面に出射する光は、散乱により前記輝度の落ち込みを解消された輝度分布の光になる。

【0112】また、との発明の液晶表示装置は、液晶表示素子の背後に、そのバックライトとして前記面発光体を配置したものであり、との面発光体は、所定の方向への出射光の輝度が高く、しかも充分な輝度の出射光が得られる出射角範囲が広いため、との液晶表示装置によれば、その表示を斜め方向から観察したときの画面の明るさの低下を少なくして、表示を充分な明るさで観察でき*

* る角度範囲を広くすることができる。

【図面の簡単な説明】

【図1】との発明の第1の実施例による面発光体のハッチングを省略した断面図。

【図2】前記面発光体に用いた輝度分布制御部材の斜視 図。

【図3】前記面発光体の出射光の輝度分布を、従来のE L素子の輝度分布およびそのEL素子の出射面に拡散板 を配置したときの輝度分布と比較して示す図。

0 【図4】との発明の第2の実施例による面発光体のハッチングを省略した断面図。

【図5】輝度分布制御部材の変形例を示す斜視図。

【図6】この発明の液晶表示装置の一実施例を示す側面図。

【図7】従来のEL素子のハッチングを省略した断面図。

【符号の説明】

10…EL素子

11…透明基板

20 12…出射側電極

13…裏側電極

14…電界発光層

20…輝度分布制御部材

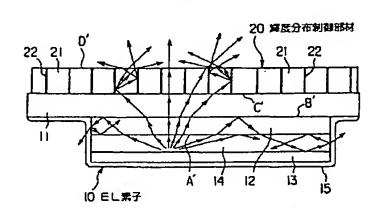
2 1 …透明部

22…散乱反射膜

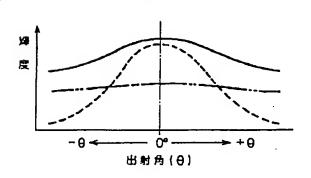
30…液晶表示素子

36…バックライト(面発光体)

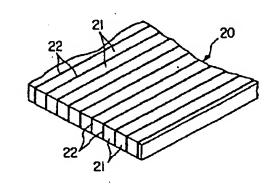
[図1]



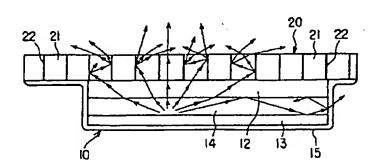
[図3]



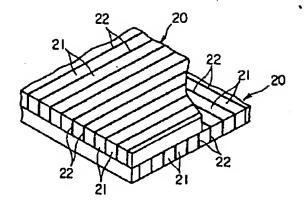
【図2】



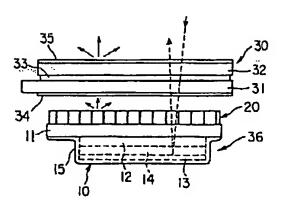
[図4]



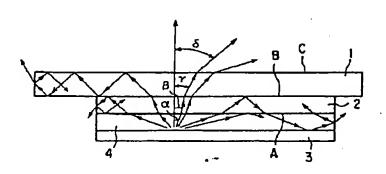
[図5]



【図6】



[図7]



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